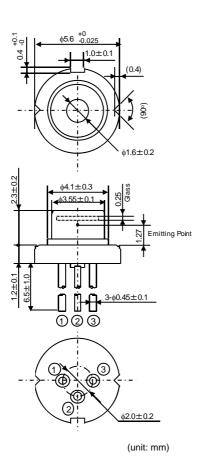
# Data Sheet

# HL63253MG

637nm/450mW AlGaInP Laser Diode

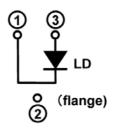


#### **Outline**



### **Internal Circuit**

## -HL63253MG



#### **Features**

- Shorter wavelength: 637nm Typ.
- High optical output power: 450mW
- Low operating current: 600mA Typ.
- Small package: \$5.6mm
- Multi transverse mode
- TM mode oscillation

# **Application**

- Laser module
- Light source of optical equipment



## **Absolute Maximum Ratings (Tc=25°C)**

Item	Symbol	Ratings	Unit
Optical output power	Ро	450	mW
LD Reverse Voltage	V <sub>R(LD)</sub>	2	V
Operating Temperature Note1)	Topr	-10 ~ +40	°C
Storage Temperature	Tstg	-40 ~ +85	°C

Note1) Operating temperature is defined by Case temperature "Tc". High increase in temperature of LD chip itself is expected during operation due to high current density. Thus, without proper heat dissipation, it is observed that no specific output power is achieved or it results to LD degradation. It is advised that sufficient measure of heat dissipation should be taken so that LD's maximum operating temperature is not exceeded during actual operation.

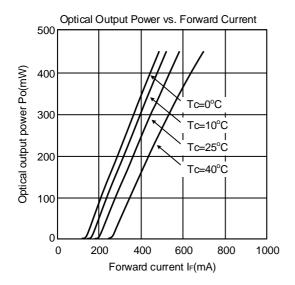
## **Optical and Electrical Characteristics (Tc=25°C)**

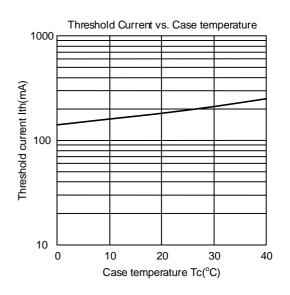
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Threshold current	Ith	-	200	250	mA	-
Operating current	lop	-	600	700	mA	Po=450mW
Operating voltage	Vop	-	2.2	2.6	V	Po=450mW
Beam divergence Parallel to the junction	θ//	1	8.5	20	o	Po=450mW, FWHM
Beam divergence Perpendicular to the junction	θΤ	25	33	40	0	Po=450mW, FWHM
Lasing Wavelength	λр	632	637	642	nm	Po=450mW

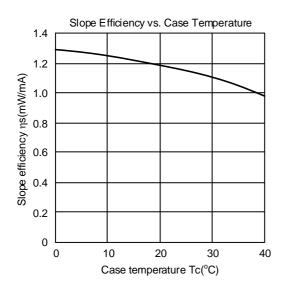
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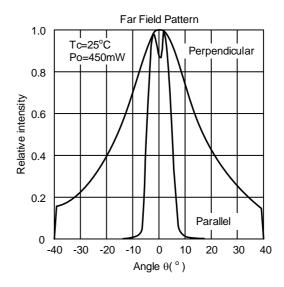


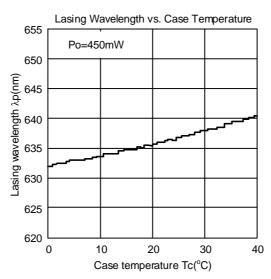
## **Typical Characteristic Curves**











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  - 2. This product (without violet laser diode) contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product. When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

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